

FCH072N60F N-Channel SuperFET[®] II FRFET[®] MOSFET

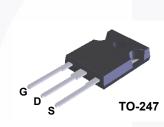
600 V, 52 A, 72 m Ω

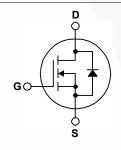
Features

- 650 V @ T_J = 150°C
- Typ. R_{DS(on)} = 65 mΩ
- Ultra Low Gate Charge (Typ. Q_g = 165 nC)
- Low Effective Output Capacitance (Typ. Coss(eff.) = 441 pF)
- 100% Avalanche Tested
- RoHS Compliant

Description

SuperFET[®] II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. SuperFET II FRFET[®] MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

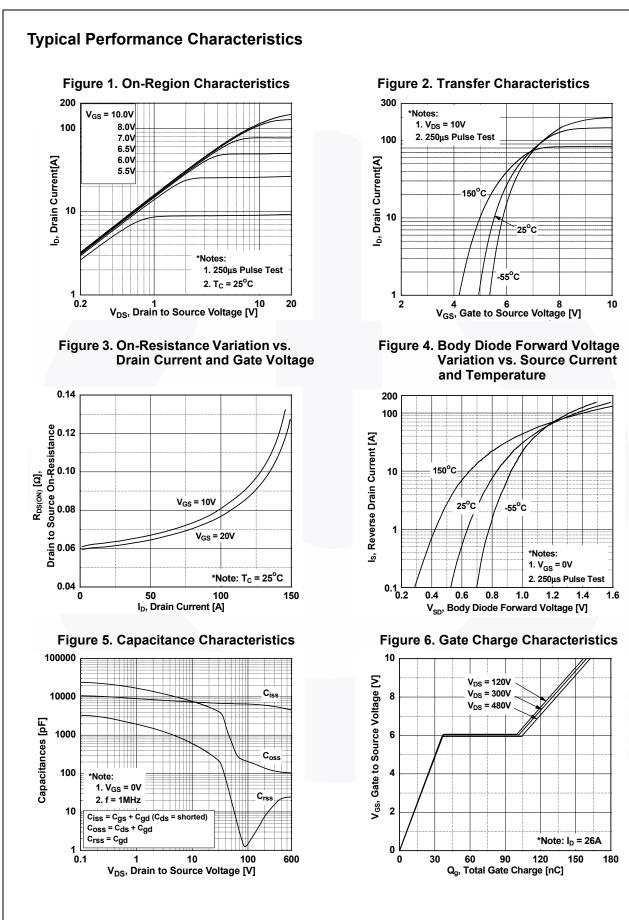
| Symbol | | Parameter | FCH072N60F | Unit |
|-----------------------------------|--|--|-------------|------|
| V _{DSS} | Drain to Source Voltage | 600 | V | |
| V _{GSS} | Gate to Source Voltage | - DC | ±20 | V |
| | | - AC (f > 1 Hz) | ±30 | v |
| I _D | Drain Current | - Continuous (T _C = 25 ^o C) | 52 | — A |
| | | - Continuous (T _C = 100 ^o C) | 33 | |
| I _{DM} | Drain Current | - Pulsed (Note 1) | 156 | Α |
| E _{AS} | Single Pulsed Avalanche Energy (Note 2) | | 1128 | mJ |
| I _{AR} | Avalanche Current (Note 1) | | 9.5 | Α |
| E _{AR} | Repetitive Avalanche Energy (Note 1) | | 4.8 | mJ |
| dv/dt | MOSFET dv/dt | 100 | V/ns | |
| | Peak Diode Recovery dv/dt | 50 | | |
| P _D | David Diasia ati an | $(T_{\rm C} = 25^{\rm o}{\rm C})$ | 481 | W |
| | Power Dissipation | - Derate Above 25°C | 3.85 | W/ºC |
| T _J , T _{STG} | Operating and Storage Temperature Range | | -55 to +150 | °C |
| TL | Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds | | 300 | °C |

Thermal Characteristics

| Symbol | Parameter | FCH072N60F | Unit | |
|-----------------------|---|------------|-------|--|
| $R_{	extsf{	heta}JC}$ | Thermal Resistance, Junction to Case, Max. | 0.26 | °C/W | |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient, Max. | 40 | °C/vv | |

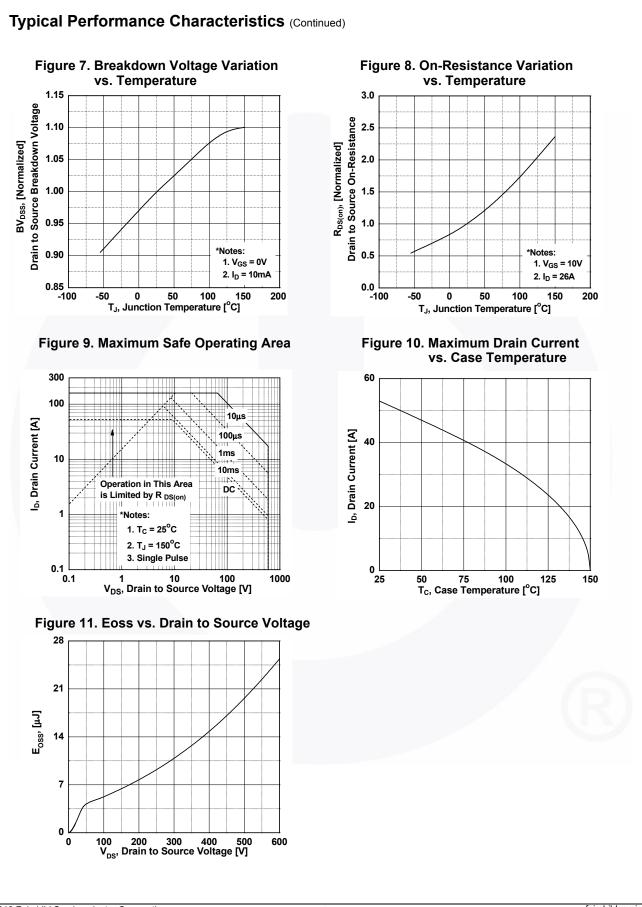
December 2013

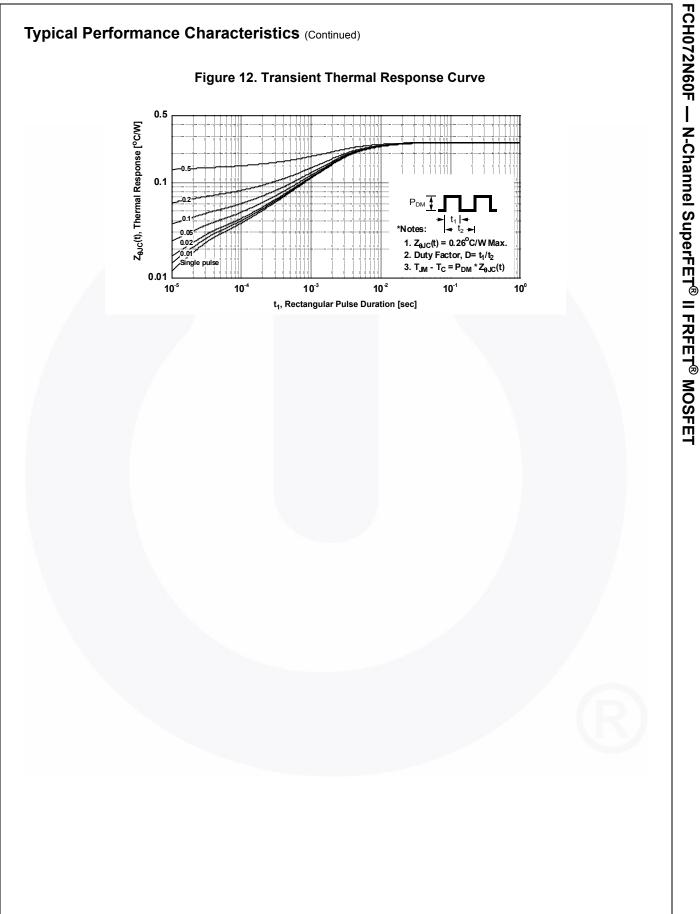
| | mber | Top Mark | Package | Packing Method | Reel Size | e | Tape Width | Qu | antity | |
|--|--|---|---|---|------------------------|------|------------|------|----------|--|
| FCH072N60F | | FCH072N60F | TO-247 | | | | N/A | 30 | 30 units | |
| Electrica | l Chara | icteristics T _C = 25°C u | inless other | wise noted. | | | | | | |
| Symbol | | Parameter | | Test Conditions | 5 | Min. | Тур. | Max. | Unit | |
| Off Charac | teristics | 6 | | | U | | | | 1 | |
| BV _{DSS} | Drain to Source Breakdown Voltage | | I _D = | 10 mA, V _{GS} = 0 V, T _C | ; = 25°C | 600 | - | - | v | |
| | | | | 10 mA, V_{GS} = 0 V, T_{C} | ; = 150 ^o C | 650 | - | - | v | |
| ΔΒV _{DSS} /ΔT _J | Breakdown Voltage Temperature Coefficient | | I _D = | I_D = 10 mA, Referenced to 25°C | | - | 0.67 | - | V/ºC | |
| DSS | Zero Gat | e Voltage Drain Current | | = 480 V, V _{GS} = 0 V | - | - | - | 1 | μA | |
| 055 | | | | = 480 V, V _{GS} = 0 V, T | _C = 125°C | - | - | 10 | μι | |
| I _{GSS} | Gate to Body Leakage Current | | V _{GS} | V_{GS} = ±20 V, V_{DS} = 0 V | | - | - | ±100 | nA | |
| On Charac | teristics | | | | | | | | | |
| V _{GS(th)} | | reshold Voltage | | $_{\rm S} = V_{\rm DS}, {\rm I}_{\rm D} = 250 \mu {\rm A}$ | | 3 | - | 5 | V | |
| R _{DS(on)} | Static Dra | ain to Source On Resistance | | ;= 10 V, I _D = 26 A | | - | 65 | 72 | mΩ | |
| 9 _{FS} | Forward | Transconductance | V _{DS} | = 20 V, I _D = 26 A | | - | 42 | - | S | |
| Dynamic C | haracte | ristics | | | | | | | | |
| C _{iss} | Input Ca | pacitance | | | | - | 6510 | 8660 | pF | |
| C _{oss} | Output C | apacitance | | = 100 V, V _{GS} = 0 V, I MHz | | - | 205 | 275 | pF | |
| 2 _{rss} | Reverse | Transfer Capacitance | . – | | | - | 1.5 | 2.5 | pF | |
| C _{oss} | Output C | apacitance | V _{DS} | = 380 V, V _{GS} = 0 V, f | = 1 MHz | - | 110 | - | pF | |
| Coss(eff.) | Effective | Output Capacitance | - | = 0 V to 480 V, V _{GS} = | | - | 441 | - | pF | |
| Q _{g(tot)} | Total Gat | e Charge at 10V | Vpc | = 380 V, I _D = 26 A, | | - | 165 | 215 | nC | |
| Q _{gs} | Gate to S | Source Gate Charge | | = 10 V | | - | 36 | - | nC | |
| Q _{gd} | Gate to D | Drain "Miller" Charge | | | (Note 4) | - | 66 | - | nC | |
| ESR | Equivale | nt Series Resistance(G-S) | f = 1 | l MHz | | - | 0.78 | - | Ω | |
| Switching | Charact | eristics | | | | | | | | |
| d(on) | - | Delay Time | | | | | 43 | 96 | ns | |
| r | | Rise Time | Vnn | V_{DD} = 380 V, I _D = 26 A, V_{GS} = 10 V, R _G = 4.7 Ω (Note 4) | | - | 38 | 86 | ns | |
| t _{d(off)} | | Delay Time | | | | - | 140 | 290 | ns | |
| <u>а(оп)</u> f | Turn-Off | | | | | - | 25 | 60 | ns | |
| Jrain Sou | 1 | e Characteristics | | | | | | | | |
| s | - | Continuous Drain to Source | e Diode For | ward Current | | - | - | 52 | A | |
| s sм | | aximum Continuous Drain to Source Diode Forward Current | | | - | - | 156 | A | | |
| SM ∕ _{SD} | | Source Diode Forward Voltac | | | - | - | 1.2 | V | | |
| | | Recovery Time | $V_{GS} = 0 V, I_{SD} = 26 A,$ | | - | 165 | - | ns | | |
| 2 _m | | Recovery Charge | $dI_{\rm F}/dt = 100 \text{ A/}\mu\text{s}$ | | - | 1.15 | | μC | | |



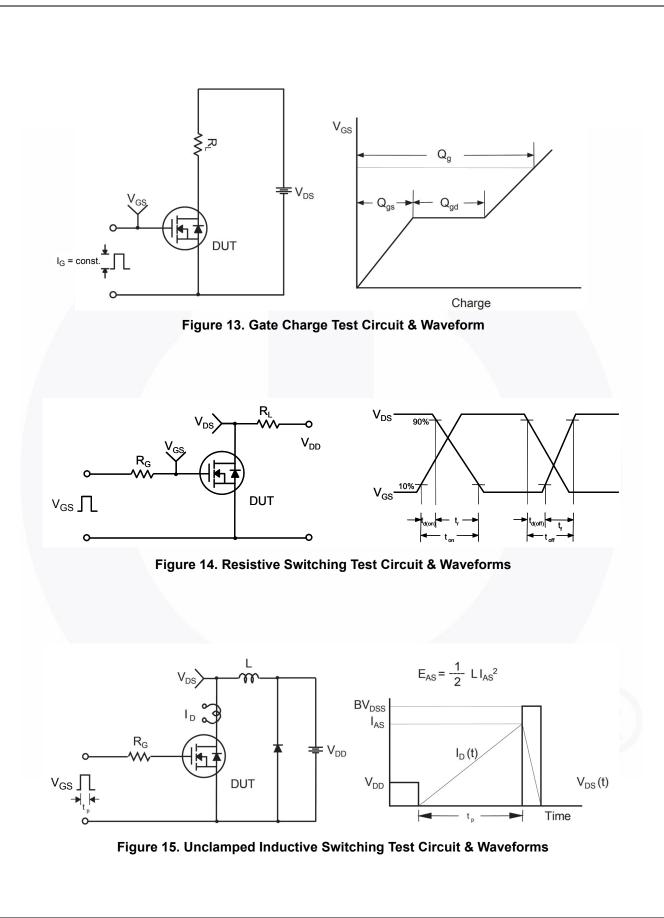
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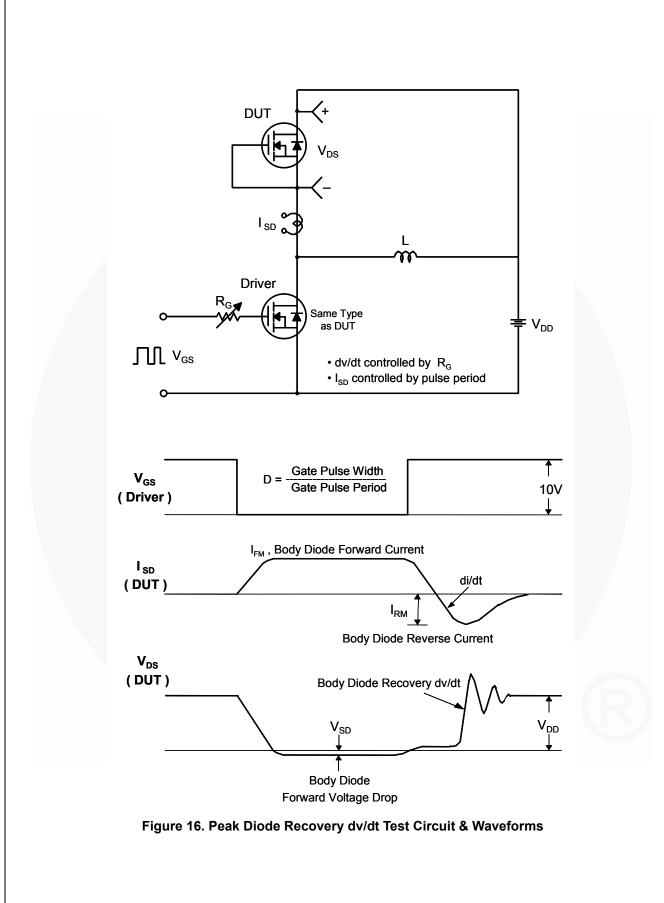


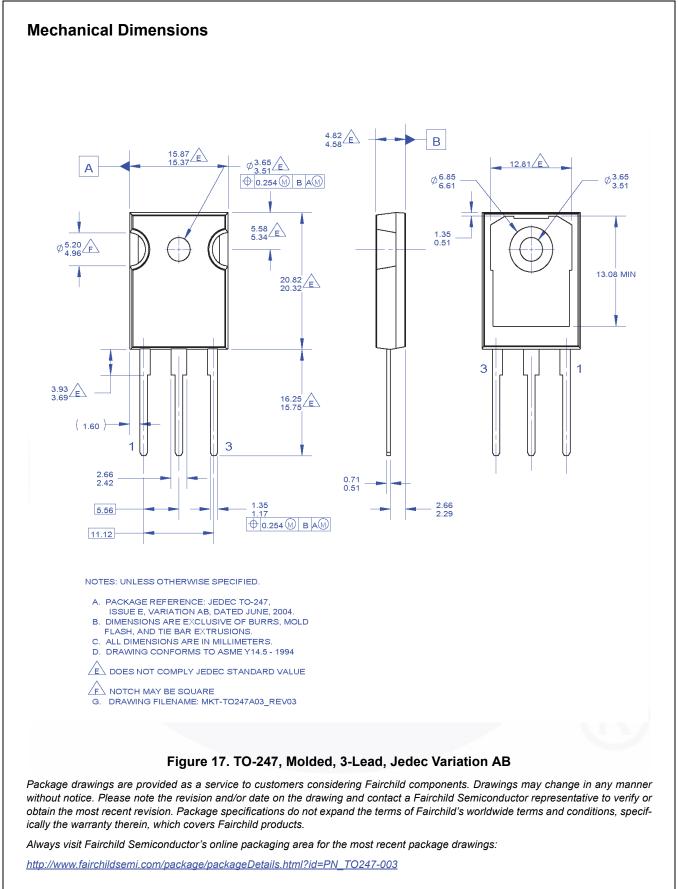
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